Quantum Manipulations of Small Josephson Junctions

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Abstract

Low-capacitance Josephson junction arrays in the parameter range where single charges can be controlled are suggested as possible physical realizations of the elements which have been considered in the context of quantum computers. We discuss single and multiple quantum bit systems. The systems are controlled by applied gate voltages, which also allow the necessary manipulation of the quantum states. We estimate that the phase coherence time is su ciently long for experimental demonstration of the principles of quantum computation.

I. IN TRODUCTION

The issue of quantum computation has attracted much attention recently [1]. Quantum algorithm s can perform certain types of calculations much faster than classical computers [2]. The basic concepts of quantum computation are quantum operations (gates) on quantum bits (qubits) and registers, i.e. arrays of qubits. A qubit can be any two-level system which can be prepared in arbitrary superpositions of its two eigenstates. Quantum computation of requires \quantum state engineering", i.e. the processes of preparation and manipulation of these quantum states in a controllable way. For quantum registers also \entangled states" (like the EPR state of two spins) have to be constructed. This necessitates a coupling between di erent qubits, and one has to be able to construct many-qubits states (many-particle states) in a controllable way. Several physical system s have been proposed as qubits

 $[\beta,4]$. A serious limitation is the requirement that the phase coherence time is su ciently long to allow the coherent quantum manipulations. The theoretically and experimentally most advanced system appears to be the chain with trapped ions $[\beta]$.

In this paper we propose an alternative system, com posed of low-capacitance Josephson junctions. The coherent tunneling of C ooper pairs mixes di erent charge states. By controlling the gate voltages we can control the strength of the mixing. The physics of coherent C ooper-pair tunneling in this system has been established before [5{7]. The algorithms of quantum computation introduce new, well-de ned rules. Their realization in experiments creates a new challenge. Here, we consider a one-bit system and we describe the possible ways of constructing quantum states. Then we focus on a two-bit system, where we propose a controllable coupling and we discuss the construction of two-bit states. In Section 2, we consider ideal system s. In Section 3 we include the coupling to a realistic external electrodynam ic environment which lim its the phase coherence tim e.

II. ID EALIZED ONE AND TW O-BIT SYSTEMS

A.One-bit system and gates.

The system we propose as a qubit is shown in Fig.1. It consists of two small superconducting grains connected by a tunnel junction. The junction is characterized by its capacitance C_J and the Josephson energy E_J . An ideal voltage source is connected to the system via two external capacitors C. We assume the total number of electrons in both grains to be even, so that at low enough temperatures all electrons are paired. Moreover, we assume that the superconducting energy gap is the largest energy in the problem. Thus we can neglect pair-breaking processes. The complete set of possible quantum states is, then, characterized by n_L and n_R – the numbers of extra Cooper pairs on the left and the right island, respectively. Since there is no tunneling through the external capacitors, the total number of the extra Cooper pairs N $n_L + n_R$ is constant. In the follow ing we

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assume N = 0. Hence the set of basis states is parameterized by the number of C oper pairs on one island or their dierence n $(n_L n_R)=2$. The Ham iltonian of this system is

$$H = \frac{(2en C V = 2)^{2}}{C + 2C_{J}} \quad E_{J} \cos(2 - \frac{1}{0});$$
(1)

where is the conjugate to the variable 2en [8] and $_{0} = \frac{h}{e}$ is the ux quantum. We consider systems where the charging energy of the internal capacitor $E_{C_{J}} = (2e)^{2} = 2C_{J}$ is much larger than E_{J} . In this regime the energy levels are determined by the charging part of the H am iltonian (1) for most values of the external voltage V. However, when V is such that the charging energies of two neighboring states $j_{1} > and j_{1} + 1 > are close to each other, the Josephson tunneling becomes relevant. Then the two eigenstates are symmetric and antisymmetric combinations of <math>j_{1} > and j_{1} + 1 > w$ ith an energy gap of E_{J} between them.

We concentrate on the voltage interval near one such degeneracy point. We dem and, however, the interval to be wide enough, so that for most values of the voltage away from degeneracy to a reasonable approximation the eigenstates are $j_1 > and j_1 + 1 > .$ Near the degeneracy points we can translate (1) to the spin- $\frac{1}{2}$ language:

$$H = \frac{eCV}{C + 2C_{J}} z + \frac{E_{J}}{2} x;$$
(2)

where j"> j_1 > and j#> j_1 + 1 > . U sing this language we can immediately propose a few one-bit operations. If, for example, one chooses the operating point (i.e. the voltage) away from the degeneracy, the logical states j_2 > and j_1 > are just j#> and j"> respectively. Then, switching the system suddenly to the degeneracy point for a time t and switching suddenly back, we can perform one of the basic one-bit operations (gates) - a spin j_2 :

To get rid of the time-dependent phases we perform all the calculations is the interaction picture, when the zero order H am iltonian is the H am iltonian at the operation point. To estimate the time-width tof the voltage pulse needed for a total spin ip, we note that a

reasonable experimental value of E_J is of the order of 1K. It cannot be chosen much smaller, since the condition $k_B T = E_J$ must be satistical. Therefore the time-width is very short: t 10⁻¹⁰ s.

However there exists an alternative way to perform a coherent spin ip, as follows: The system is pushed adiabatically to the degeneracy point. Then the ac voltage with frequency E_{J} =h is applied. The process is completely analogous to the paramagnetic resonance (here the constant magnetic eld component is in the x-direction, while the oscillating one is in the z-direction). The tim e-width of the ac pulse needed for the total spin ip depends on its amplitude, therefore it can be chosen much longer then 10⁻¹⁰s.

One can also perform an operation which changes only the relative phase between the the states j #> and j ">. To this end one should suddenly switch to another voltage away from the degeneracy and switch suddenly to the original point. The phase is acquired due to di erence in energy gaps between the two points.

B.Two-bit system .

To perform two-bit operations (gates) which result in entangled states, one has to couple the qubits in a controllable way. The best situation would be one where the coupling can be switched o , leaving the qubits uncoupled when no operations are performed. Unfortunately, this option appears di cult to realize in m icroscopic and m esoscopic systems. As an alternative we suggest for a system with a weak constant coupling between the qubits. W e will show that by tuning the energy gaps of the individual qubits we can change the e ective strength of the coupling. W e propose to couple two qubits using an inductance as shown in Fig.(2). One can easily see that if L = 0 the system reduces to two uncoupled qubits, while if L = 1 the C oulom b interaction couples both qubits strongly. Therefore, we are interested in low values of L (the exact criterion to be specified). The H am iltonian describing this system is

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$$H = \frac{X}{_{i=1;2}^{i=1;2}} \left(\frac{(2en_{i} \quad V_{i}C_{t})^{2}}{2C_{J}} + \frac{E_{J}\cos(2 \quad -\frac{i}{0}=2)}{(0=2)} + \frac{q^{2}}{2(2C_{t})} + \frac{2}{2L} - \frac{e(n_{1} \quad n_{2})q}{C_{J}} + \frac{e^{2}C_{t}}{C_{J}^{2}} (n_{1} + n_{2})^{2};$$
(4)

where q denotes the total charge on the external capacitors of both qubits, is its conjugate variable, and $C_t^{-1} = C_J^{-1} + 2C^{-1}$. The oscillator described by q and variables produces an electric mean eld coupling between the qubits for frequencies smaller than $!_{LC} = 1 = \frac{p}{2C_t L}$. In order to have this coupling in a wide enough voltage interval around the degeneracy point, we dem and that

$$A \quad \frac{h!_{LC}}{E_J} \quad 1:$$
 (5)

A lthough the integration over q and can be performed exactly starting with (4), the resulting e ective action is not simple. We prefer an alternative way. First we perform a canonical transformation

i = 1; 2, which results in a new Ham iltonian (we om it the tildes):

$$H = \frac{X}{_{i=1,2}} \left(\frac{(2en_{i} \quad C \quad V_{i}=2)^{2}}{C + 2C_{J}} + \frac{q^{2}}{2(2C_{t})} + \frac{2}{2L} \right)^{2} \qquad E_{J} \cos \left(\frac{2}{_{0}=2} + (-1)^{i} \frac{C_{t}}{C_{J}} + (-1)^{i} \frac{C_{t}}{C_{J}} \right)^{2}$$
(7)

Now we make an additional assumption

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 > $\frac{C_{J}}{C_{t}} \frac{0}{2}^{2}$: (8)

This assumption is, actually, necessary if one wishes to have Josephson tunneling terms in the Ham iltonian. Qualitatively, one can observe from (7), that if (8) does not hold, the $E_{J}\cos(::)$ terms are washed out. Below we will obtain this result in a more rigorous way.

A ssum ing the condition (8) we expand the $E_{J}\cos(::)$ terms of (7) in powers of and we neglect powers higher than linear. Then we can perform the integrations over q and ,

which are again Gaussian. As a result we obtain an e ective Ham iltonian, which consists of two one-bit Ham iltonians (1) and a coupling term :

$$H_{int} = E_{L} \sin \frac{2}{0=2} \sin \frac{1}{1} \sin \frac{2}{0=2} e^{2} ;$$
 (9)

where

$$E_{L} = 8 \frac{{}^{2}C_{t}^{2}}{C_{J}^{2}} \frac{E_{J}^{2}L}{{}^{2}C_{J}} \frac{2}{0} :$$
(10)

This Ham iltonian is valid for frequencies which are smaller than $!_{LC}$. In the spin- $\frac{1}{2}$ language it is

$$H_{int} = \frac{E_{L}}{4} \left(\begin{array}{cc} (1) & (2) \\ y & y \end{array} \right)^{2} :$$
(11)

The mixed term in (11) is important in certain situations. A ssume that E_L is comparable to E_J and the voltages V_1 and V_2 are such that both qubits are out of degeneracy. Then, to a good approximation, the eigenstates of the two-bit system without coupling are j##>, j#">, j"#> and j"">. In a general situation, these states are separated by energies which are larger or much larger than E_J . Therefore, the e ect of the coupling is small. If, how ever, a pair of these state is degenerate, the coupling may lift the degeneracy, changing the eigenstates drastically. For example, if $V_1 = V_2$, the states j#"> and j"#> are degenerate. In this case the correct eigenstates are: $\frac{1}{P_2}(j#"> + j"#>)$ and $\frac{1}{P_2}(j#"> j"#>)$ with the energy splitting E_L between them.

Now we are ready to propose a way to perform two-bit operations which will result in entangled states. For this we choose the operating points for the qubits at di erent voltages. Then we switch suddenly the voltages to be equal for a time t and switch suddenly back. The result is a \generalized" spin- ip, which may be described in the basis fj##>, j#">, j"#>, j""> g by a matrix:

$$U_{\frac{ip}{2}}^{(2)}(t) = \begin{cases} 0 & 0 & 0 & 0 \\ 0 & \cos \frac{E_{L} t}{2h} & \sin \frac{E_{L} t}{2h} & 0 \\ 0 & \sin \frac{E_{L} t}{2h} & \cos \frac{E_{L} t}{2h} & 0 \\ 0 & 0 & 0 & 1 \end{cases}$$
(12)

The gate (12) together with the one-bit gates (3) constitute a universal set, i.e., they are su cient for quantum computation.

Instead of applying very short voltage pulses, one again can move the system adiabatically to the degeneracy point ($V_1 = V_2$), and, then, apply an ac voltage pulse in the antisymmetric channel V_1 $V_2 = A \exp(iE_L t=h)$.

III.CIRCUIT EFFECTS AND DISSIPATION

A.One-bit system . Energy relaxation out of the degeneracy point.

The idealized picture outlined above has to be corrected with respect to the possible dissipation mechanisms, which, as usual, cause decoherence and energy relaxation. In this paper we focus on the elect of ohm ic dissipation in the circuit, which originates mostly from the voltage sources. We also consider the elect of LC resonances in the circuit. We neglect quasi-particle tunneling since it is strongly suppressed at low temperatures and low voltages. The system is shown in Fig.3. We include the inductance L explicitly for two reasons. First, we would like to couple the bath of oscillators to a continuous charge variable, rather than directly coupling them to the discrete variable n. Second, we would like to treat the LC oscillatory mode separately from the bath oscillators, since it plays an in portant role in the two-bit system. The Ham iltonian for this system is:

$$H = \frac{(2en V C_t)^2}{2C_J} = E_J \cos 2 - \frac{1}{0} = 2 + \frac{q^2}{2C_t} + \frac{2}{2L} = \frac{2enq}{C_J} + H_{bath}(q); \quad (13)$$

where

$$H_{bath}(q) = \frac{x}{j} \frac{4}{2m_{j}} \frac{p_{j}^{2}}{2m_{j}} + \frac{m_{j}!_{j}^{2}}{2} x_{j} \frac{\frac{1}{2}}{m_{j}!_{j}^{2}} q^{5}; \qquad (14)$$

and J (w) $\frac{P}{2} \int_{j}^{2} \frac{j}{m_{j}!_{j}} (! !_{j}) = R !$. In (13) and (14) the variable q denotes the charge on the external capacitors, while is its conjugate variable. The coupling to the bath (14) produces the usual dissipative term -Rq - in the equation of motion for q. A lthough the Hamiltonian (13) is quite transparent, another equivalent form is more convenient. It is obtained after two consequent canonical transform ations:

$$\mathbf{q} = \mathbf{q}; \qquad \qquad \sim = + \frac{P}{j \frac{j}{m_j ! j^2}} \mathbf{p}_j;$$

$$\mathbf{x}_j = \mathbf{x}_j \quad \frac{j}{m_j ! j^2} \mathbf{q}; \qquad \mathbf{p}_j = \mathbf{p}_j;$$

$$(15)$$

and

$$q = q \quad \frac{2 enC_t}{C_J}; \qquad = ~;$$

$$n = n; \qquad = + \frac{C_t}{C_J}~: \qquad (16)$$

Now the Ham iltonian takes the form :

$$H = \frac{(2en CV=2)^{2}}{C+2C_{J}} \qquad E_{J}\cos^{''}\frac{2}{_{0}=2} \qquad \frac{C_{t}}{C_{J}}\sim^{''} + \frac{q^{2}}{2C_{t}} + H_{bath}^{0}(\sim): \quad (17)$$

where

$$H_{bath}^{0}(~) = \frac{X}{j} \frac{p_{j}^{2}}{2m_{j}} + \frac{m_{j}!_{j}^{2}}{2} x_{j}^{\#} + \frac{(~ p_{j}\frac{j}{m_{j}!_{j}^{2}}p_{j})^{2}}{2L} :$$
(18)

The two forms (13) and (17) di erm ostly in the de nition of the phase variable conjugated to q. If L is smallenough, the variable uctuates in a small interval around zero. However, the uctuations of ~ are around a bath-dependent value, which may uctuate strongly itself. Below we will see that both form smay be useful in di erent situations.

First, we estimate the energy relaxation time, r, due to the ohmic dissipation. We assume that the system is away from the degeneracy point and is prepared in one of its eigenstates ($j_1 > or j_1 + 1 >$) at the beginning. We use the Hamiltonian in the second form (17). The part of (17) connecting the states $j_1 > and j_1 + 1 > is$

$$H_{t} = \frac{E_{J}}{2} \exp i \frac{2}{0=2} \exp \frac{2}{1-2} \exp \frac{2}{1-2} \frac{C_{t}}{C_{J}} + hc::$$
(19)

At this point we can directly apply the standard G olden Rule results for the transition rate from the state $j_1 > t_0$ to the state $j_1 + 1 > [9\{12]:$

$$(E) = \frac{1}{2h} E_{J}^{2} P(E);$$
 (20)

$$P(E) = \frac{1}{2 h} \int_{-1}^{Z_{1}} dt \exp \left(4 \frac{C_{t}^{2}}{C_{J}^{2}} K(t) + \frac{i}{h} Et\right)^{\#}; \qquad (21)$$

$$K (t) = 2 \int_{0}^{Z_{1}} \frac{d!}{!} \frac{ReZ_{t}(!)}{R_{K}} \operatorname{coth} \frac{h!}{2k_{B}T} \operatorname{cos}(!t) 1] \operatorname{isin}(!t) ; \qquad (22)$$

$$Z_{t}^{1} = i! C_{t} + \frac{1}{R + i! L}$$
 (23)

Here E is the energy gap between the two states. The qualitative behavior of the system is, as usual, controlled by the dimensionless conductance $g = \frac{R_K}{4R}$. In our system a remarkable renorm alization of the controlling parameter g occurs: from (21) one can observe that $g = \frac{C_T^2}{C_t^2}g$ is the relevant parameter. Thus, making the external capacitances C much smaller than the internal one $-C_J$, we can drastically reduce the e ect of the dissipation. Physically, this means that the uctuations produced by the resistor are screened by the small capacitors, and, therefore, they have little e ect on the Josephson junction.

To be more concrete, we exploit the asymptotic form ula for P (E) [12]

P(E) =
$$\frac{\exp(2 - g)}{(2 - g)} \frac{1}{E} \frac{\pi}{g} \frac{E}{E_{C_t}}^{\#_{2-g}}$$
; (24)

where (::) is the G am m a function. For large values of g we obtain:

r

$$\frac{1}{(E)} \qquad \operatorname{op} \frac{g}{2^2} \frac{E}{E_J} ; \qquad (25)$$

where $_{\rm op}$ $\frac{h}{E_{\rm J}}$ is the operation time (see (3)).

B.One-bit system . Circuit e ects at the degeneracy point.

At the degeneracy point the system is equivalent to the two-level model with a weak ohm ic dissipation, which was extensively studied during the last decades [13]. It is well known that when g 1 coherent oscillations take place. These oscillations make the spinip operation (3) possible. The decay time of the coherent oscillations is given by

$$_{d} \quad \frac{g}{2^{2}}\frac{h}{E_{J}} = \frac{g}{2^{2}} _{op} ; \qquad (26)$$

and the energy gap E_J is slightly renorm alized:

$$E_{J} ! E_{J} \frac{E_{J}}{h!_{c}} \stackrel{\frac{1}{g-1}}{:} \qquad (27)$$

The physical cut-o $!_{c}$ is usually a system -dependent property. For a pure ohm ic dissipation caused by a metallic resistor it may be as high as the D rude frequency. However, when additional capacitances and inductances are present in the circuit, the relevant cut-o may be low ered to the characteristic LC frequencies.

As was said above, the LC phase uctuations can wash out the Josephson coupling. To see this, we begin with the rst form of the H am iltonian (13) and we integrate out the bath variables and the oscillatory mode variables – ;q. The partition function reads:

$$Z = \frac{X Z_{n_0}}{D nD}$$

$$\exp \frac{1}{h} \int_{0}^{n_0} d(2ei n H_0(n;)) \int_{0}^{Z_h Z_h} dd^{0} \frac{1}{2}G(\int_{0}^{0} n()n(0); (28)$$

where

$$H_{0} = \frac{(2en \quad V C_{t})^{2}}{2C_{J}} \quad E_{J} \cos 2 \frac{1}{0} = 2$$
(29)

and

$$G(!_{n}) = \frac{4C_{t}e^{2}}{C_{J}^{2}} \frac{1}{(1 + C_{t}L!_{n}^{2} + C_{t}Rj!_{n}j)} :$$
(30)

Below we will show, that in the relevant parameters' range, the following inequality holds

$$\frac{1}{C_t R} \quad \frac{p}{LC_t} \quad \frac{R}{L} :$$
 (31)

Therefore, the natural cuto for (30) would be $!_{c} = !_{LC} = \frac{p_{LC_{t}}}{LC_{t}}$. To make a rough estimation we replace (30) by

$$G(!_{n}) = \frac{4C_{t}e^{2}}{C_{J}^{2}}(1 - C_{t}L!_{n}^{2} - C_{t}R); !_{n} < !_{c}$$

$$G(!_{n}) = 0; !_{n} > !_{c}: \qquad (32)$$

The kernel (32) is a sum of a trivial charging energy renormalization (the rst term), the usual ohmic dissipation (the third term) and the inductive term, which we will focus on. We apply the standard charge representation technique [14], expanding $\exp \frac{h}{h} \frac{R_h}{0} d E_J \cos(2 - \frac{1}{0^{-2}})^i$ in powers of E_J and integrating over term by term. One obtains, then, a path integral over integer charge paths with instantaneous \jumps" between the di erent values of n. Each such \jump" contributes a multiplicative factor of $E_J=2h$ to the weight of the path. It turns out that the inductive term contributes another multiplicative factor for each \jump", so that E_J is renorm alized as:

$$\mathbf{E}_{J} = \mathbf{E}_{J} \exp \left(\frac{2\mathbf{L}\mathbf{C}_{t}^{2}!_{c}}{\mathbf{R}_{K}\mathbf{C}_{J}^{2}} \right)^{!} \qquad (33)$$

O ne can immediately observe that the condition that E_J is not renormalized to zero coincides with the small uctuations condition (8). We would like to emphasize that the phase uctuations which may wash out the Josephson coupling in (33) are related to the \weakly uctuating" phase , rather than to the \strongly uctuating" ~ (see (15)). Thus the elects of the inductance and the dissipation may be well separated in this regime. Another way of viewing this separation is by noting that the LC phase uctuations are fast, therefore they electively wash out the slower processes (like Josephson tunneling). On the other hand the phase uctuations, caused by the resistor, are large only at low frequencies, thus they cannot wash out the faster processes.

C.Two-bit system .Circuit e ects.

In this subsection we show that the coupling term (9) survives when the ohm ic dissipation is present in the circuit. The analyzed system is shown in Fig.(4). We include the auxiliary inductances L_a in order to couple the dissipation bathes to continuous charge variable, rather than directly to the principal variables n and m. Finally we take L_a ! 0. The H am iltonian is given by:

$$H = \frac{X}{_{i=1,2}} \left(\frac{(2en_{i} - V_{i}C_{t})^{2}}{2C_{J}} - E_{J}\cos 2 - \frac{i}{_{0}=2} \right) + \frac{q_{i}^{2}}{2C_{t}} - \frac{2en_{i}q_{i}}{C_{J}} + H_{bath}(q_{i}) + \frac{(1 + _{2})^{2}}{4L_{a}} + \frac{(1 + _{2})^{2}}{4(2L + L_{a})} \right)$$
(34)

Here q_1 is the charge on the left-m ost external capacitor, while q_2 is the charge on the rightm ost external capacitor. $_1$ and $_2$ are their conjugate phases (weakly uctuating ones). W e m ake a canonical transform ation

$$\mathbf{g}_{i} = \mathbf{q}_{i} \quad \frac{2\mathrm{en}_{i}C_{t}}{C_{J}}; \quad \mathbf{a} = \mathbf{i};$$

$$\mathbf{n}_{i} = \mathbf{n}_{i}; \quad \mathbf{a}_{i} = \mathbf{i} + \frac{C_{t}}{C_{J}}; \quad \mathbf{i};$$
(35)

(i = 1; 2) and the new Ham iltonian looks like (we om it the tildes):

$$H = \frac{X}{_{i=1;2}} \left(\frac{(2en_{i} \quad C \quad V_{i}=2)^{2}}{C + 2C_{J}} \quad E_{J} \cos \frac{2}{_{0}=2} \quad i \quad \frac{C_{t}}{C_{J}} \quad i \quad + \frac{q_{i}^{2}}{2C_{t}} + H_{bath} \quad q_{i} + \frac{C_{t}}{C_{J}} 2en_{i} \right) + \frac{(_{1} + _{2})^{2}}{4L_{a}} + \frac{(_{1} + _{2})^{2}}{4(2L + L_{a})} :$$
(36)

A lthough the canonical transform ation (35) books equivalent to (16), there is one essential di erence. In (16) we used the phase variable which included the bath uctuations, while in (35) we keep the weakly uctuating phases $_1$ and $_2$. Next, we expand the $E_J \cos(::)$ term s in $_1$ and $_2$ and we integrate over the baths and over the two oscillatory m odes. Finally we assume L_a ! 0. One can directly check that in the nondiagonal channel the m ixed term of (9) emerges, accompanied with a bunch of other terms which are sm all at low frequency. Thus, the two-bit coupling, crucial for the quantum computation, is stable under the in uence of the dissipation.

IV . D ISC U SSIO N

Several conditions were assumed in this Letter in order to guarantee the validity of our results. Here we state these conditions once more and discuss the appropriate ranges of parameters. We start with E_J 1K as a suitable experimental condition. To satisfy $E_J = E_{C_J}$ we take $C_J = 10^{16}$ F, which is an experimentally accessible value. As we would like A to be large (5), it seems that L and C_t should be as small as possible. However, the two-bit coupling energy, E_L (10), should be larger than the temperature of the experiment. A ssum ing a reasonable working temperature of 20 m K, we dem and $E_L = 0.1$ K. From (5) and (10) we get $C_t = E_L C_J^2 A^2 = e^2$. To have a wide enough operation voltage interval we take

A 10, and obtain C_t 10¹⁷ 10¹⁶ F and L 10⁸ 10⁷ H. Thus the renorm alization of g is of the order of 10, and $_r = _{op}$ 10⁶ 10⁶ (assuming the realistic value R 100) (25). Finally we observe that in this range of parameters the inequalities (8) and (31) are always satisticated. We conclude that the quantum manipulations we have discussed in this paper can be tested experimentally using the currently available lithographic and cryogenic techniques. Application of the Josephson junction system as an element of a quantum computer is a more subtle issue, demanding either the fabrication of junctions with $C_J < 10^{-16}$ F, or a further reduction of the working temperature.

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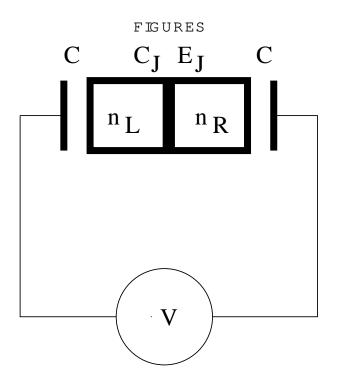


FIG.1. An idealized qubit system .

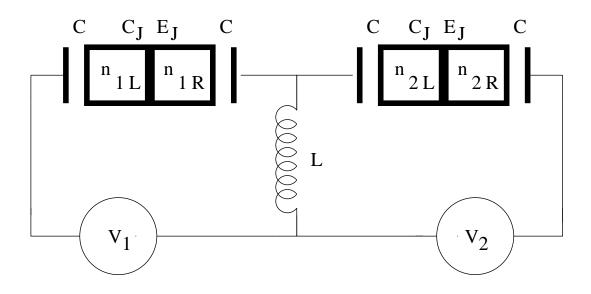


FIG.2. An idealized two-bit system.

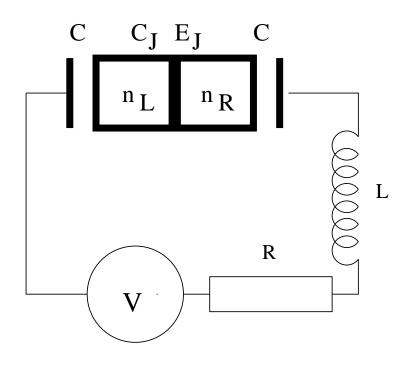


FIG.3. A qubit with dissipation.

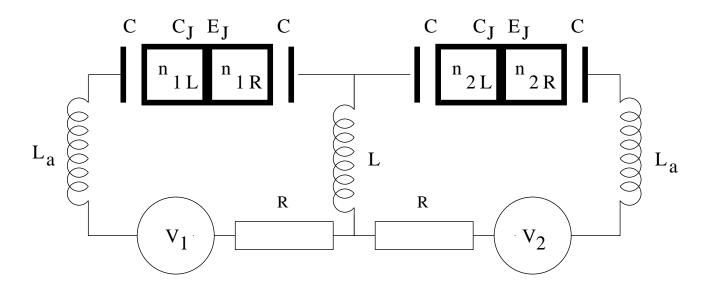


FIG.4. Two-bit system with dissipation.